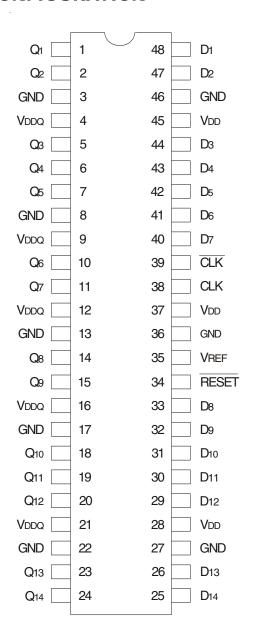
PIN CONFIGURATION



TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

| Symbol | Description | Max. | Unit |
|-------------------|-------------------------------------------------------|-------------------|------|
| VDD or VDDQ | Supply Voltage Range | -0.5 to 3.6 | V |
| VI ⁽²⁾ | Vi ⁽²⁾ Input Voltage Range -0.5 to VDD +0. | | V |
| Vo ⁽³⁾ | Output Voltage Range | -0.5 to VDDQ +0.5 | V |
| lik | Input Clamp Current, Vi < 0 | -50 | mA |
| Іок | Output Clamp Current, | ±50 | mA |
| | Vo < 0 or Vo > VDDQ | | |
| lo | Continuous Output Current, | ±50 | mA |
| | Vo = 0 to VDDQ | | |
| Vdd | Continuous Current through each | ±100 | mA |
| | VDD, VDDQ or GND | | |
| Tstg | Storage Temperature Range | -65 to +150 | °C |

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
 permanent damage to the device. This is a stress rating only and functional operation
 of the device at these or any other conditions above those indicated in the operational
 sections of this specification is not implied. Exposure to absolute maximum rating
 conditions for extended periods may affect reliability.
- 2. The input and output negative voltage ratings may be exceeded if the ratings of the I/P and O/P clamp current are observed.
- 3. The output current will flow if the following conditions are observed:
 - a) Output in HIGH state
 - b) Vo = VDDQ

FUNCTION TABLE (1)

| RESET | CLK | CLK | D | Q Outputs |
|-------|----------|--------------|---|-------------------|
| Н | ↑ | \downarrow | L | L |
| Н | ↑ | \downarrow | Н | Н |
| Н | L or H | L or H | Х | Qo ⁽²⁾ |
| L | Х | Х | Χ | L |

NOTES:

- 1. H = HIGH Voltage Level
- L = LOW Voltage Level
- X = Don't Care
- ↑ = LOW to HIGH
- ↓ = HIGH to LOW
- 2. Qo = Output level before the indicated steady-state conditions were established.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = 0°C to +70°C, VDD = $2.5V \pm 0.2V$, VDDQ = $2.5V \pm 0.2V$

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|--------|--------------------------------|-------------------------------------------------------------------------------------|-----------|------|------|----------|
| VIK | Control Inputs | VDD = 2.3V, II = -18mA | _ | _ | -1.2 | V |
| Vон | | VDD = 2.3V to 2.7V, IOH = -100μA | VDD - 0.2 | _ | | V |
| | | VDD = 2.3V, IOH = -8mA | 1.95 | _ | ı | |
| Vol | | VDD = 2.3V to 2.7V, IOL = 100μA | _ | _ | 0.2 | V |
| | | VDD = 2.3V, IOL = 8mA | _ | _ | 0.35 | |
| lı | All Inputs | VDD = 2.7V, VI = VDD or GND | _ | _ | ±5 | μΑ |
| IDD | Static Standby | Io = 0, VDD = 2.7V, RESET = GND | _ | _ | 0.01 | mA |
| | Static Operating | $IO = 0$, $VDD = 2.7V$, $\overline{RESET} = VDD$, $VI = VIH$ (AC) or VIL (AC) | _ | 6 | _ | |
| IDDD | Dynamic Operating (Clock Only) | $IO = 0$, $VDD = 2.7V$, $\overline{RESET} = VDD$, $VI = VIH$ (AC) or VIL (AC), | _ | _ | _ | μA/Clock |
| | | CLK and CLK Switching 50% Duty Cycle. | | | | MHz |
| | Dynamic Operating | IO = 0, VDD = 2.7V, RESET = VDD, VI = VIH (AC) or VIL (AC), | _ | _ | _ | μA/Clock |
| | (Per Each Data Input) | CLK and CLK Switching 50% Duty Cycle. One Data Input | | | | MHz/Data |
| | | Switching at Half Clock Frequency, 50% Duty Cycle. | | | | Input |
| | Data Inputs | $VDD = 2.5V$, $VI = VREF \pm 310mV$ | 2.5 | _ | 3.5 | |
| Сі | CLK and CLK | VICR = 1.25V, VI (PP) = 360mV | 2.5 | _ | 3.5 | pF |
| | RESET | VI = VDD or GND | _ | _ | _ | |

OPERATING CHARACTERISTICS, TA = 25°C (1)

| Symbol | Parameter | | Min. | Тур. ⁽¹⁾ | Max. | Unit |
|--------|---------------------------------|-------------|-------------|---------------------|------------|------|
| VDD | Supply Voltage | | VDDQ | _ | 2.7 | V |
| VDDQ | Output Supply Voltage | | 2.3 | 2.5 | 2.7 | V |
| VREF | Reference Voltage (VREF=VDDQ/2) | | 1.15 | 1.25 | 1.35 | V |
| VTT | Termination Voltage | | VREF-40mV | Vref | VREF+ 40mV | V |
| Vı | Input Voltage | | 0 | _ | Vdd | V |
| VIH | AC High-Level Input Voltage | Data Inputs | VREF+ 310mV | _ | _ | V |
| VIL | AC Low-Level Input Voltage | Data Inputs | _ | _ | VREF-310mV | V |
| VIH | DC High-Level Input Voltage | Data Inputs | VREF+ 150mV | _ | _ | V |
| VIL | DC Low-Level Input Voltage | Data Inputs | _ | _ | VREF-150mV | V |
| VIH | High-Level Input Voltage | RESET | 1.7 | _ | _ | V |
| VIL | Low-Level Input Voltage | RESET | _ | _ | 0.7 | V |
| Vicr | Common-Mode Input Range | CLK, CLK | 0.97 | _ | 1.53 | V |
| VI(PP) | Peak-to-Peak Input Voltage | CLK, CLK | 360 | _ | _ | mV |
| Іон | High-Level Output Current | | _ | _ | -20 | mA |
| loL | Low-Level Output Current | | | | 20 | |
| TA | Operating Free-Air Temperature | | 0 | _ | +70 | °C |

NOTE

^{1.} The RESET input of the device must be held at VDD or GND to ensure proper device operation.

TIMING REQUIREMENTS OVER RECOMMENDED OPERATING FREE-AIR TEMPERATURE RANGE

| | | | $V_{DD} = 2.5V \pm 0.2V$ | | |
|--------|--------------------------------------------------|------------------------|--------------------------|------|------|
| Symbol | Parameter | | Min. | Max. | Unit |
| CLOCK | Clock Frequency | | _ | 200 | MHz |
| tw | Pulse Duration, CLK, CLK HIGH or LOW | | 2.5 | | ns |
| tact | Differential Inputs Active Time ⁽¹⁾ | | _ | 22 | ns |
| tinact | Differential Inputs Inactive Time ⁽²⁾ | | _ | 22 | ns |
| tsu | Setup Time, Fast Slew Rate ^(3,5) | Data Before CLK↑, CLK↓ | 0.75 | _ | ns |
| | Setup Time, Slow Slew Rate(4,5) | | 0.9 | _ | ns |
| ₩ | Hold Time, Fast Slew Rate ^(3,5) | Data Before CLK↑, CLK↓ | 0.75 | _ | ns |
| | Hold Time, Slow Slew Rate ^(2,5) | | 0.9 | _ | ns |

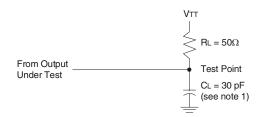
NOTES:

- 1. Data inputs must be low a minimum time of tact max., after RESET is taken HIGH.
- 2. Data and clock inputs must be held at valid levels (not floating) a minimum time of tinact max., after RESET is taken LOW.
- 3. For data signal input slew rate is $\geq 1 \text{V/ns}$.
- 4. For data signal input slew rate is ≥0.5V/ns and <1V/ns.
- 5. CLK, CLK signal input slew rates are ≥1V/ns.

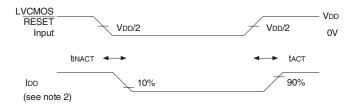
SWITCHING CHARACTERISTICS OVER RECOMMENDED FREE-AIR OPERATING RANGE (UNLESS OTHERWISE NOTED)

| | | $VDD = 2.5V \pm 0.2V$ | | |
|-------------|------------------|-----------------------|------|------|
| Symbol | Parameter | Min | Max. | Unit |
| fMAX | | 200 | _ | MHz |
| t PD | CLK and CLK to Q | 1.1 | 2.8 | ns |
| tphL tphL | RESET to Q | _ | 5 | ns |

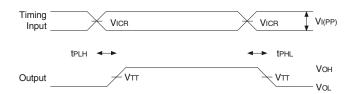
TEST CIRCUITS AND WAVEFORMS (VDD = 2.5V ± 0.2V)



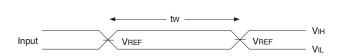
Load Circuit



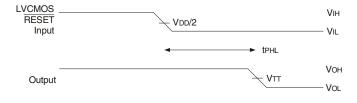
Voltage and Current Waveforms Inputs Active and Inactive Times



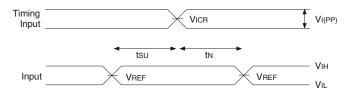
Voltage Waveforms - Propagation Delay Times



Voltage Waveforms - Pulse Duration



Voltage Waveforms - Propagation Delay Times

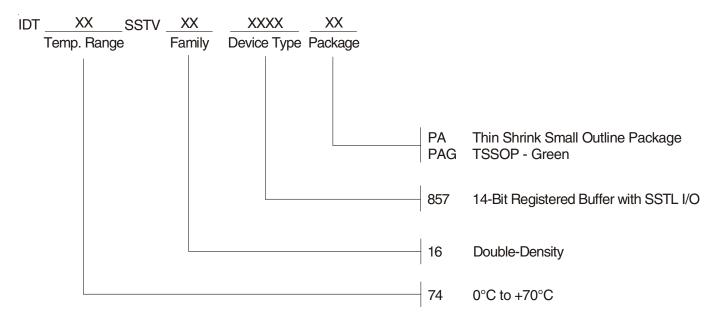


Voltage Waveforms - Setup and Hold Times

NOTES:

- 1. CL includes probe and jig capacitance.
- 2. IDD tested with clock and data inputs held at VDD or GND, and Io = 0mA.
- 3. All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, Zo = 50 Ω , input slew rate = 1 V/ns \pm 20% (unless otherwise specified).
- 4. The outputs are measured one at a time with one transition per measurement.
- 5. VTT = VREF = VDDQ/2
- 6. VIH = VREF + 310mV (AC voltage levels) for differential inputs. VIH = VDD for LVCMOS input.
- 7. VIL = VREF 310mV (AC voltage levels) for differential inputs. VIL = GND for LVCMOS input.
- 8. tplh and tphl are the same as tpd.

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